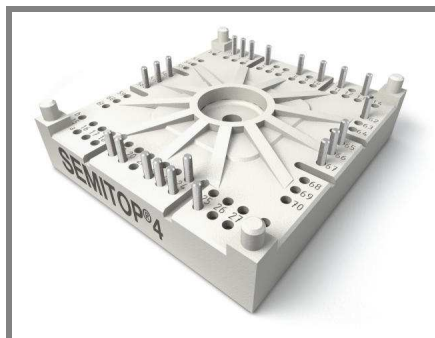


SK50GH12T4T



SEMITOP®4

IGBT module

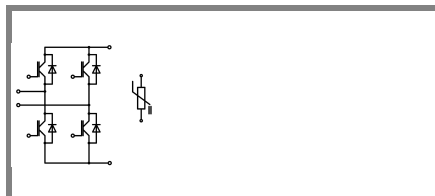
SK50GH12T4T

Features

- One screw mounting module
- Fully compatible with SEMITOP®1,2,3
- Improved thermal performances by aluminium oxide substrate
- New IGBT4 Technology
- CAL 4 technology FWD
- Integrated NTC Temperature sensor

Typical Applications*

- Voltage regulator

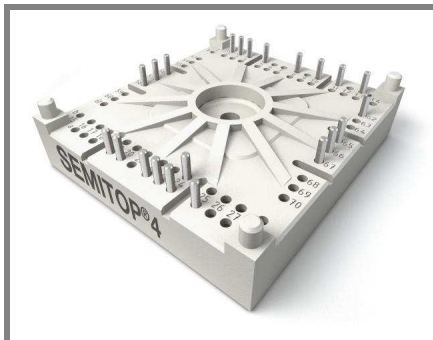


GH-T

Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT			
V_{CES}	$T_j = 25\text{ °C}$	1200	V
I_C	$T_j = 175\text{ °C}$	$T_s = 25\text{ °C}$	75
		$T_s = 70\text{ °C}$	60
I_{CRM}	$I_{CRM} = 3 \times I_{Cnom}$, $t_p \leq 1\text{ ms}$	150	A
V_{GES}		± 20	V
t_{psc}	$V_{CC} = 800\text{ V}$; $V_{GE} \leq 15\text{ V}$; $T_j = 150\text{ °C}$ $V_{CES} < 1200\text{ V}$	10	μs
Inverse Diode			
I_F	$T_j = 175\text{ °C}$	$T_s = 25\text{ °C}$	56
		$T_s = 70\text{ °C}$	45
I_{FRM}	$I_{FRM} = 3 \times I_{Fnom}$, $t_p \leq 1\text{ ms}$	150	A
I_{FSM}	$t_p = 10\text{ ms}$; half sine wave $T_j = 150\text{ °C}$	335	A
Module			
$I_{t(RMS)}$			A
T_{vj}		-40 ... +175	$^{\circ}\text{C}$
T_{stg}		-40 ... +125	$^{\circ}\text{C}$
V_{isol}	AC, 1 min.	2500	V

Characteristics		$T_c = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 1,7\text{ mA}$	5	5,8	6,5	V
I_{CES}	$V_{GE} = 0\text{ V}$, $V_{CE} = V_{CES}$	$T_j = 25\text{ °C}$		1,0	mA
		$T_j = 125\text{ °C}$		0,4	mA
I_{GES}	$V_{CE} = 0\text{ V}$, $V_{GE} = 20\text{ V}$			600	nA
V_{CE0}		$T_j = 25\text{ °C}$	0,8	0,9	V
		$T_j = 150\text{ °C}$	0,7	0,8	V
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}$	20		m Ω
		$T_j = 150\text{ °C}$	30		m Ω
$V_{CE(sat)}$	$I_{Cnom} = 50\text{ A}$, $V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}_{chiplev.}$	1,8	2	V
		$T_j = 150\text{ °C}_{chiplev.}$	2,2	2,4	V
C_{ies}	$V_{CE} = 25$, $V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	5,54		nF
C_{oes}			0,41		nF
C_{res}			0,32		nF
Q_G	$V_{GE} = -7V...+15V$		375		nC
R_{Gint}	$T_j = 25\text{ °C}$		4		Ω
$t_{d(on)}$	$R_{Gon} = 32\ \Omega$ $di/dt = 920\text{ A}/\mu\text{s}$	$V_{CC} = 600\text{ V}$ $I_C = 50\text{ A}$ $T_j = 150\text{ °C}$	63		ns
t_r			65		ns
E_{on}			8,3		mJ
$t_{d(off)}$	$R_{Goff} = 32\ \Omega$	$T_j = 150\text{ °C}$	521		ns
t_f			80		ns
E_{off}			5		mJ
$R_{th(j-s)}$	per IGBT		0,65		K/W

SK50GH12T4T



SEMITOP®4

IGBT module

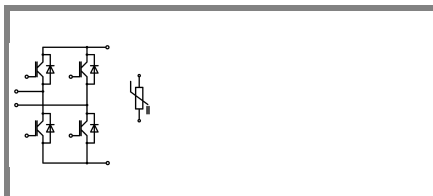
SK50GH12T4T

Features

- One screw mounting module
- Fully compatible with SEMITOP®1,2,3
- Improved thermal performances by aluminium oxide substrate
- New IGBT4 Technology
- CAL 4 technology FWD
- Integrated NTC Temperature sensor

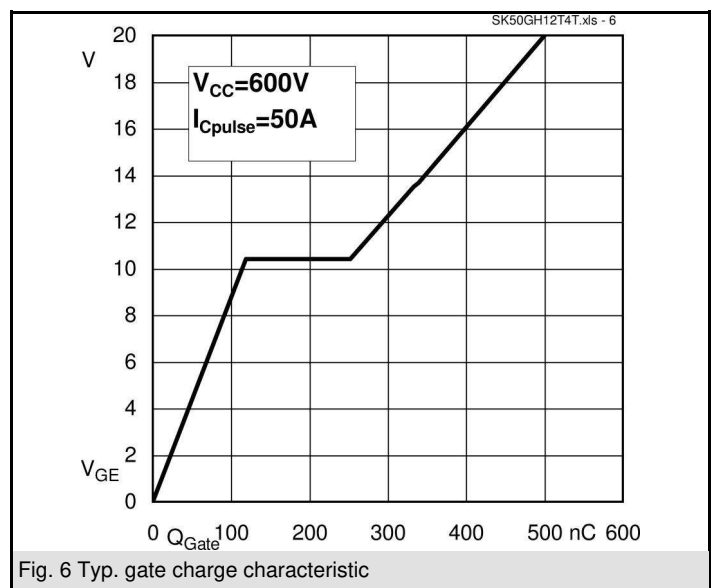
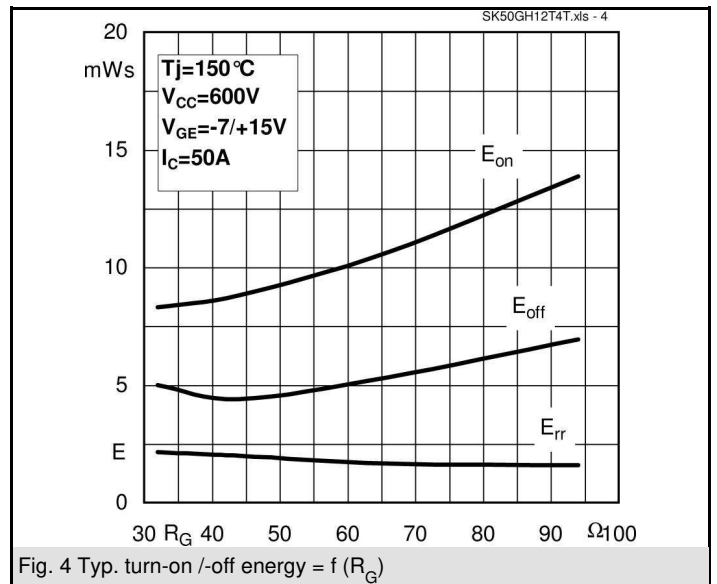
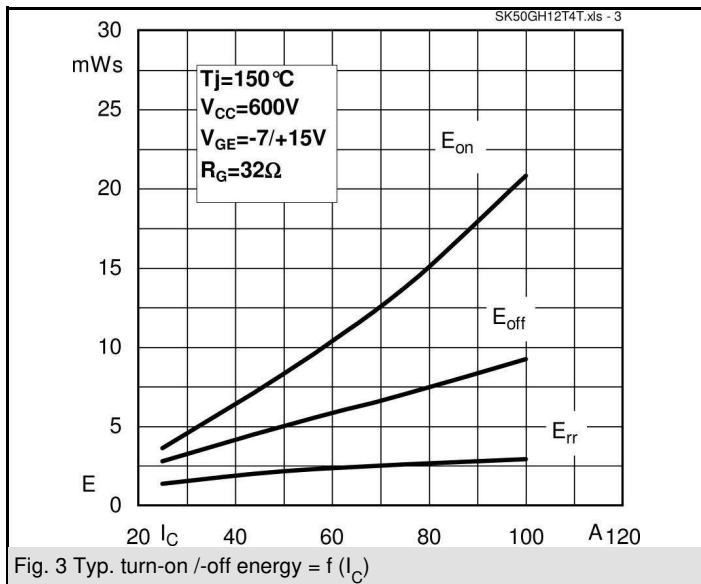
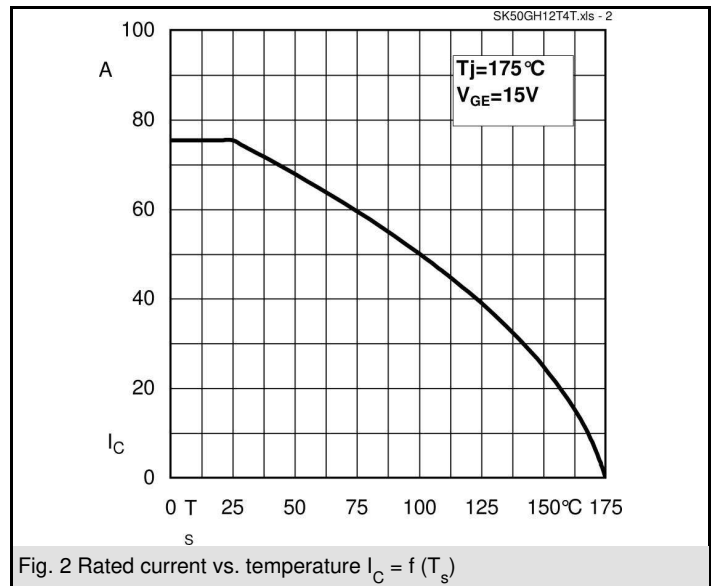
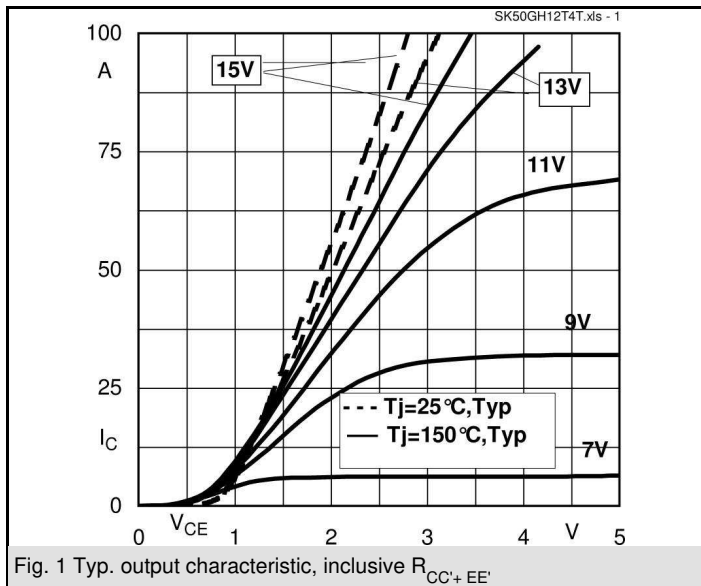
Typical Applications*

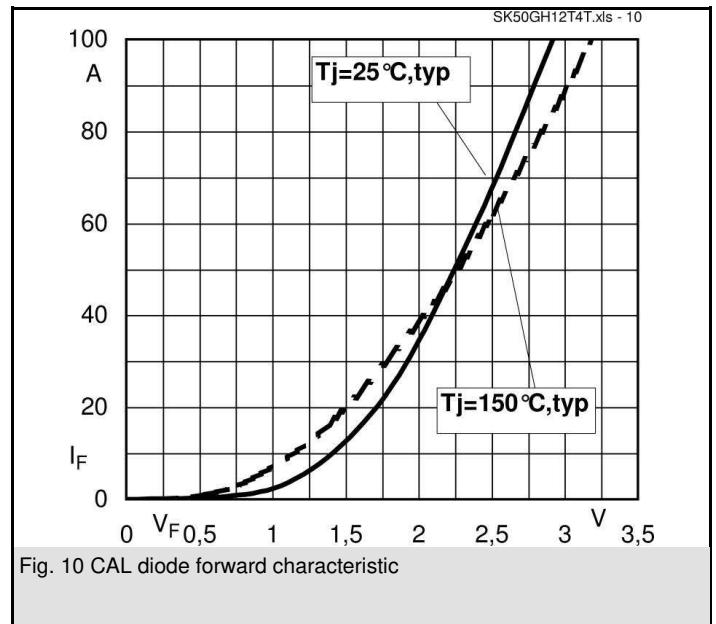
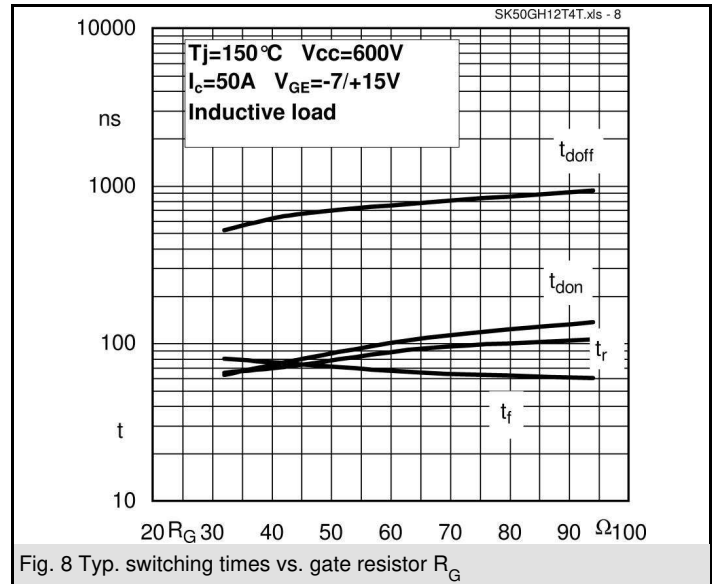
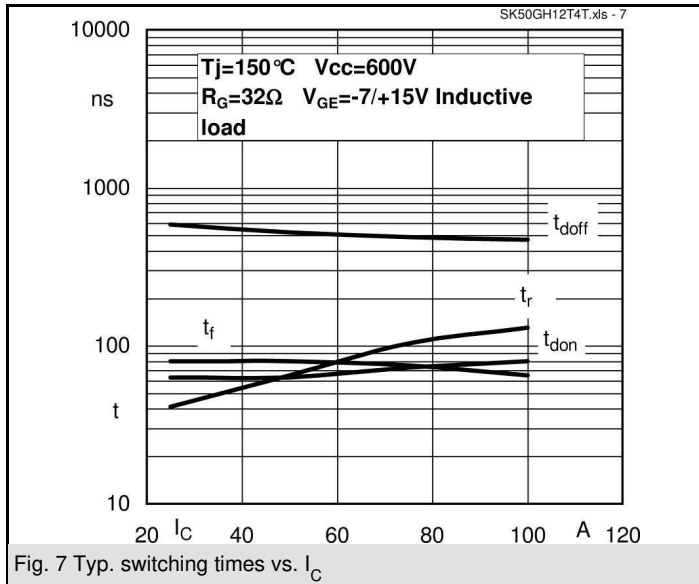
- Voltage regulator

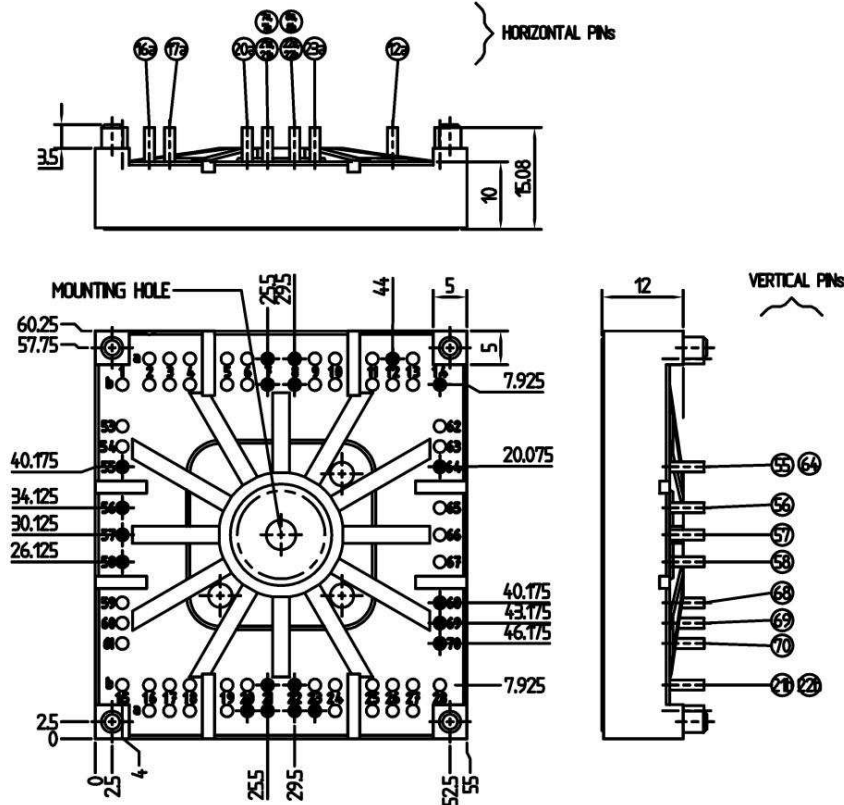


GH-T

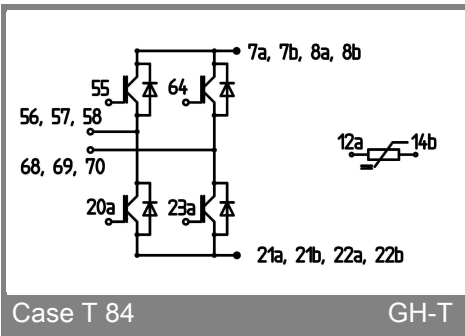
Characteristics			min.	typ.	max.	Units
Symbol	Conditions					
Inverse Diode						
$V_F = V_{EC}$	$I_{Fnom} = 50 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}_{\text{chiplev.}}$		2,2	2,5	V
		$T_j = 150 \text{ }^\circ\text{C}_{\text{chiplev.}}$		2,1	2,45	V
V_{F0}		$T_j = 25 \text{ }^\circ\text{C}$		1,3	1,5	V
		$T_j = 150 \text{ }^\circ\text{C}$		0,9	1,1	V
r_F		$T_j = 25 \text{ }^\circ\text{C}$		18		mΩ
		$T_j = 150 \text{ }^\circ\text{C}$		24		mΩ
I_{RRM}	$I_F = 50 \text{ A}$	$T_j = 150 \text{ }^\circ\text{C}$		30		A
Q_{rr}	$di/dt = 920 \text{ A}/\mu\text{s}$			7,2		μC
E_{rr}	$V_{CC} = 600 \text{ V}$			2,15		mJ
$R_{th(j-s)D}$	per diode			1,05		K/W
Freewheeling Diode						
$V_F = V_{EC}$	$I_{Fnom} = \text{A}; V_{GE} = \text{V}$	$T_j = \text{ }^\circ\text{C}_{\text{chiplev.}}$				V
V_{F0}		$T_j = \text{ }^\circ\text{C}$				V
r_F		$T_j = \text{ }^\circ\text{C}$				V
I_{RRM}	$I_F = \text{A}$	$T_j = \text{ }^\circ\text{C}$				A
Q_{rr}						μC
E_{rr}						mJ
	per diode					K/W
M_s	to heat sink		2,5		2,75	Nm
w				60		g
Temperature sensor						
R_{100}	$T_s = 100^\circ\text{C} (R_{25} = 5\text{k}\Omega)$			493±5%		Ω







Case T84 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T 84

GH-T

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

*IMPORTANT INFORMATION AND WARNINGS

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